# NCE N-Channel Super Trench Power MOSFET

## Description

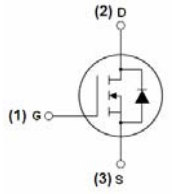
The NCEP8814AS uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and $Q_g$. This device is ideal for high-frequency switching and synchronous rectification.

## General Features

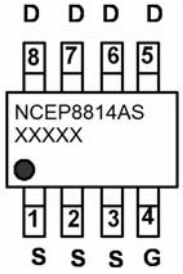
- $V_{DS}$ =88V,$I_D$ =14A
  $R_{DS(ON)}$=8.8mΩ (typical) @ $V_{GS}$=10V
  $R_{DS(ON)}$=9.8mΩ (typical) @ $V_{GS}$=4.5V
- Excellent gate charge x $R_{DS(on)}$ product(FOM)
- Very low on-resistance $R_{DS(on)}$
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

## Application

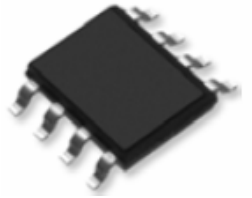
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification




**Schematic diagram**




**Marking and pin assignment**



**SOP-8 top view**

## Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|---|---|---|---|---|---|
| NCEP8814AS | NCEP8814AS | SOP-8 | Ø330mm | 12mm | 4000 units |

## Absolute Maximum Ratings ($T_A$=25℃unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|---|---|---|
| Drain-Source Voltage | $V_{DS}$ | 88 | V |
| Gate-Source Voltage | $V_{GS}$ | ±20 | V |
| Drain Current-Continuous | $I_D$ | 14 | A |
| Drain Current-Continuous($T_C$=100℃) | $I_D$ (100℃) | 10 | A |
| Pulsed Drain Current | $I_{DM}$ | 56 | A |
| Maximum Power Dissipation | $P_D$ | 3.5 | W |
| Single pulse avalanche energy (Note 5) | $E_{AS}$ | 230 | mJ |
| Operating Junction and Storage Temperature Range | $T_J$,$T_{STG}$ | -55 To 150 | ℃ |

## Thermal Characteristic

| | | | |
|---|---|---|---|
| Thermal Resistance,Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | 41.7 | ℃/W |

## Electrical Characteristics ($T_A$=25℃unless otherwise noted)

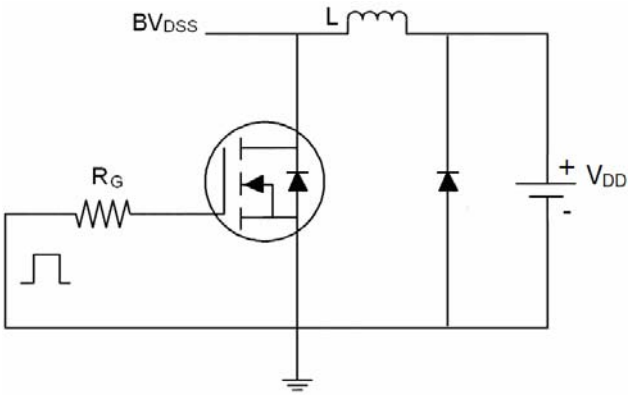
| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| **Off Characteristics** | | | | | | |
| Drain-Source Breakdown Voltage | $BV_{DSS}$ | $V_{GS}$=0V $I_D$=250μA | 88 | - | - | V |
| Zero Gate Voltage Drain Current | $I_{DSS}$ | $V_{DS}$=88V,$V_{GS}$=0V | - | - | 1 | μA |
| Gate-Body Leakage Current | $I_{GSS}$ | $V_{GS}$=±20V,$V_{DS}$=0V | - | - | ±100 | nA |
| **On Characteristics** (Note 3) | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}$=$V_{GS}$,$I_D$=250μA | 1.2 | 1.7 | 2.2 | V |
| Drain-Source On-State Resistance | $R_{DS(ON)}$ | $V_{GS}$=10V, $I_D$=14A | - | 8.8 | 10.2 | mΩ |
| | | $V_{GS}$=4.5V, $I_D$=10A | - | 9.8 | 11.2 | mΩ |
| Forward Transconductance | $g_{FS}$ | $V_{DS}$=5V,$I_D$=14A | - | 30 | - | S |
| **Dynamic Characteristics** (Note4) | | | | | | |
| Input Capacitance | $C_{lss}$ | $V_{DS}$=40V,$V_{GS}$=0V, F=1.0MHz | - | 3696 | | PF |
| Output Capacitance | $C_{oss}$ | | - | 250 | | PF |
| Reverse Transfer Capacitance | $C_{rss}$ | | - | 40 | | PF |
| **Switching Characteristics** (Note 4) | | | | | | |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD}$=40V,$I_D$=14A $V_{GS}$=10V,$R_G$=1.6Ω | - | 11 | - | nS |
| Turn-on Rise Time | $t_r$ | | - | 7 | - | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 30 | - | nS |
| Turn-Off Fall Time | $t_f$ | | - | 4 | - | nS |
| Total Gate Charge | $Q_g$ | $V_{DS}$=40V,$I_D$=14A, $V_{GS}$=10V | - | 54 | - | nC |
| Gate-Source Charge | $Q_{gs}$ | | - | 13 | - | nC |
| Gate-Drain Charge | $Q_{gd}$ | | - | 7 | - | nC |
| **Drain-Source Diode Characteristics** | | | | | | |
| Diode Forward Voltage (Note 3) | $V_{SD}$ | $V_{GS}$=0V,$I_S$=14A | - | - | 1.2 | V |
| Diode Forward Current (Note 2) | $I_S$ | | - | - | 14 | A |
| Reverse Recovery Time | $t_{rr}$ | $T_J$ = 25°C, $I_F$ = $I_S$ di/dt = 100A/μs (Note3) | - | 78 | - | nS |
| Reverse Recovery Charge | Qrr | | - | 149 | - | nC |

## Notes:

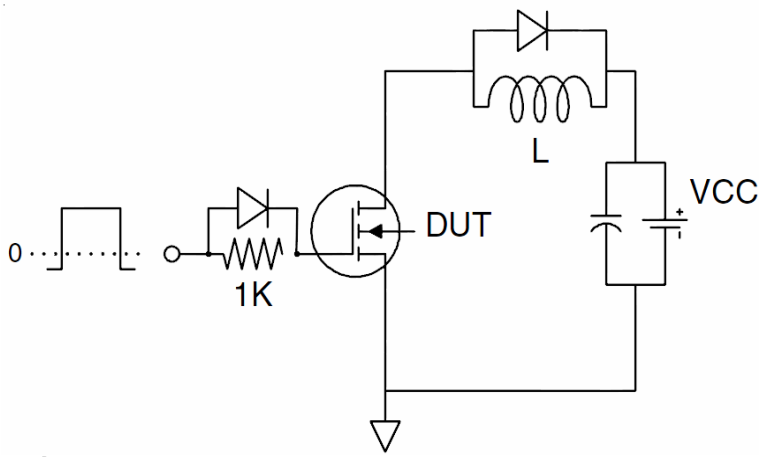
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production

## Test Circuit

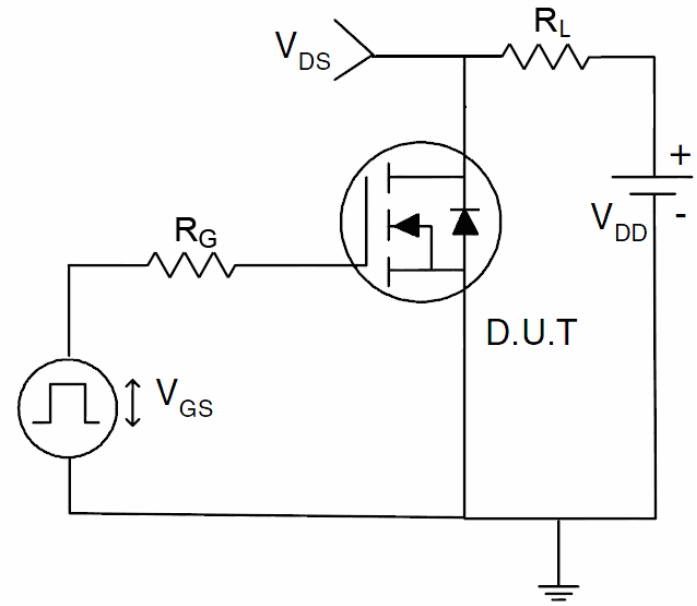
### 1) $E_{AS}$ test Circuit




### 2) Gate charge test Circuit




### 3) Switch Time Test Circuit



## Typical Electrical and Thermal Characteristics

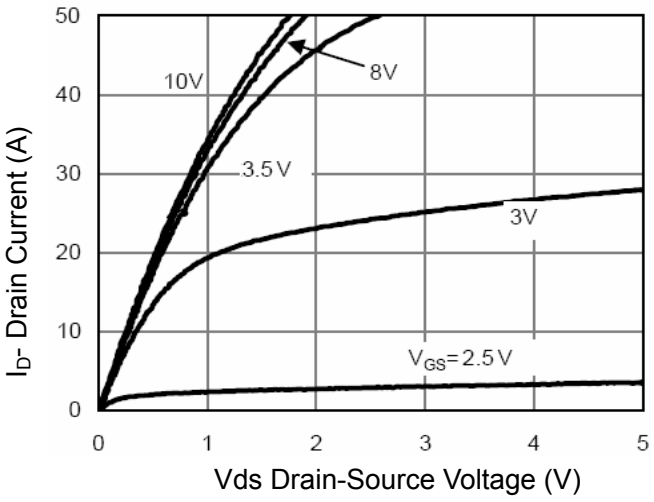



**Figure 1 Output Characteristics**

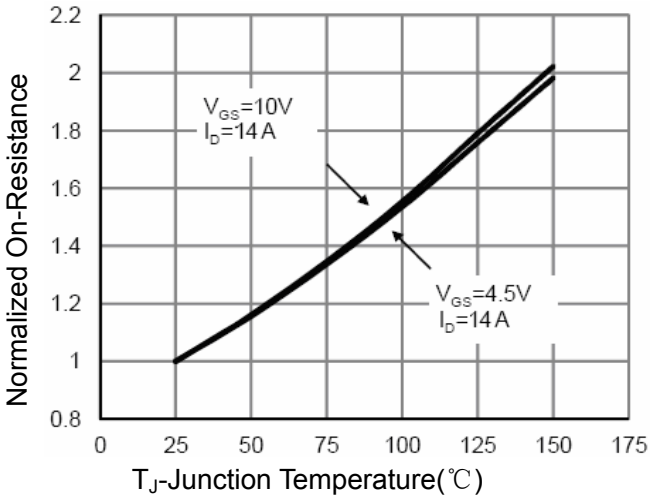



**Figure 4 Rdson-Junction Temperature**

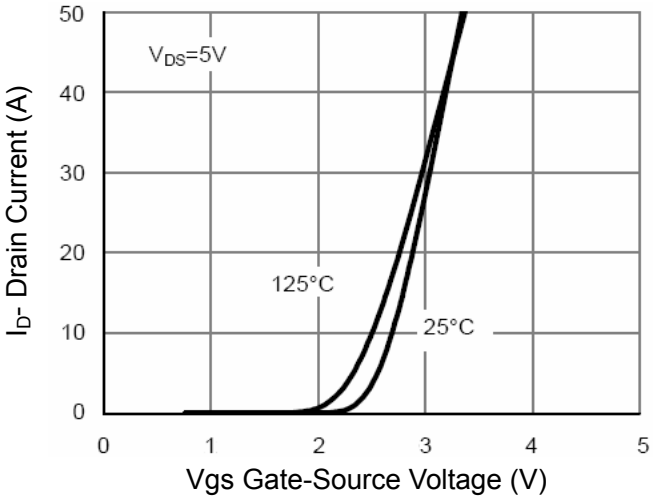



**Figure 2 Transfer Characteristics**

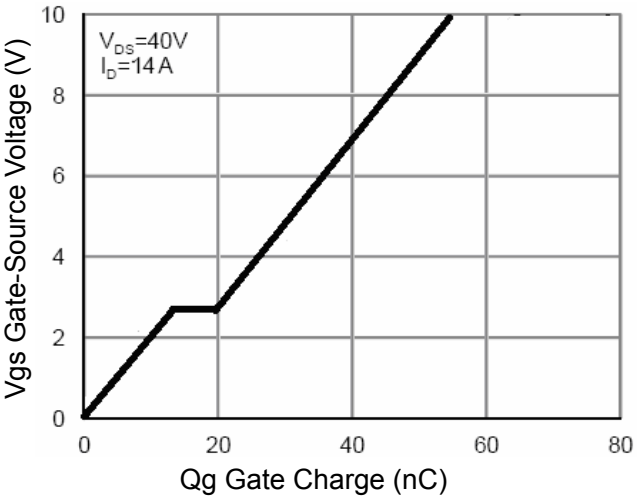



**Figure 5 Gate Charge**

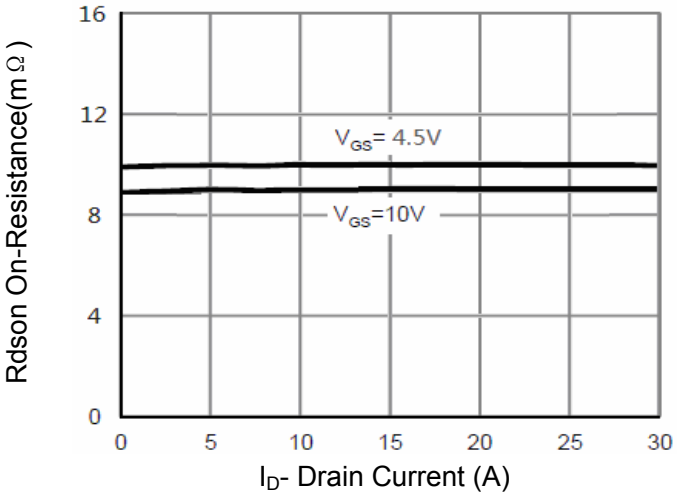



**Figure 3 Rdson- Drain Current**

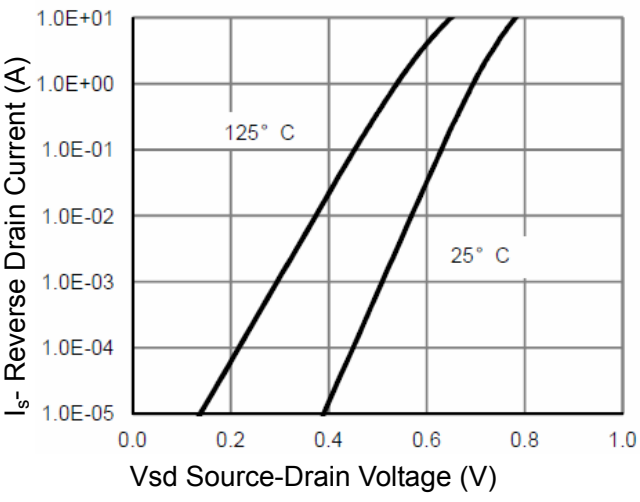



**Figure 6 Source- Drain Diode Forward**

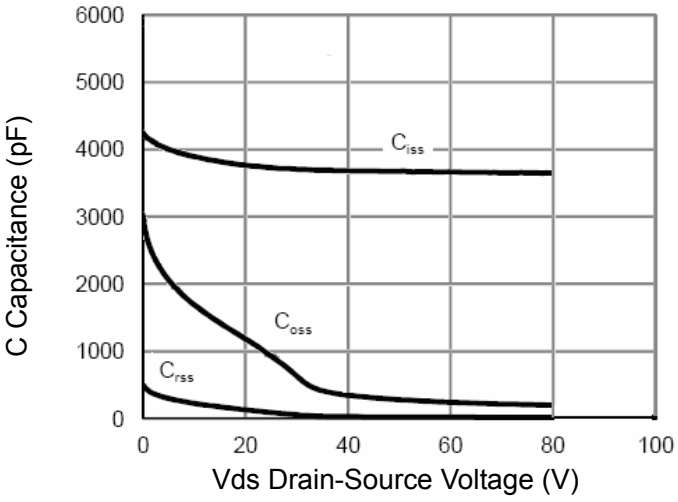



**Figure 7 Capacitance vs Vds**

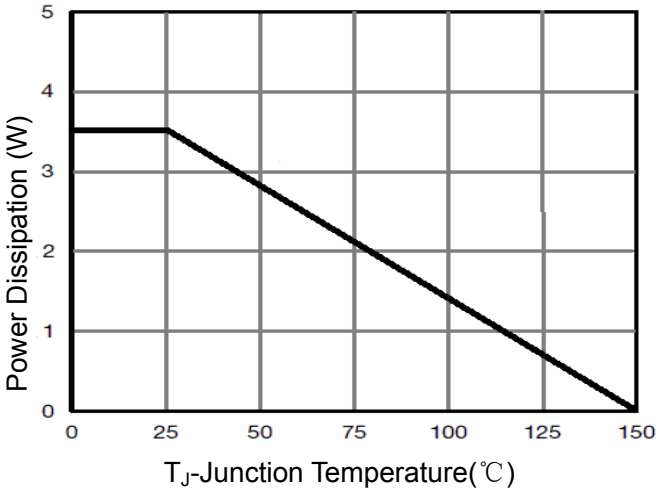



**Figure 9 Power De-rating**

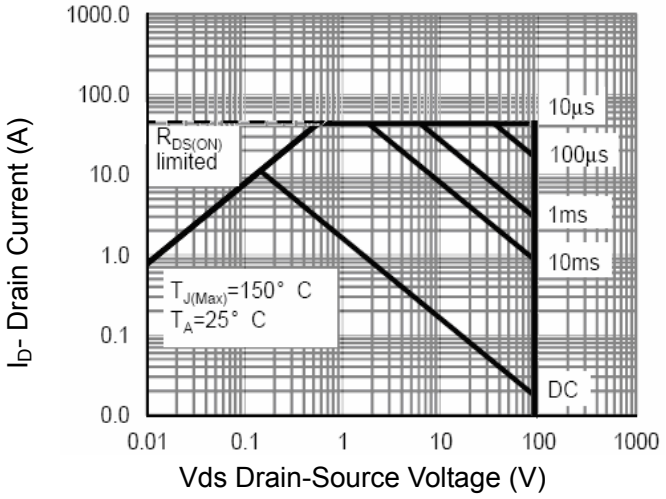



**Figure 8 Safe Operation Area**

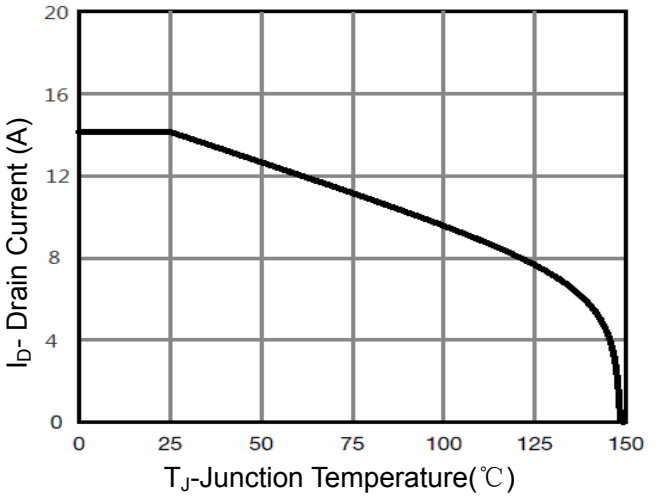



**Figure 10 Current De-rating**

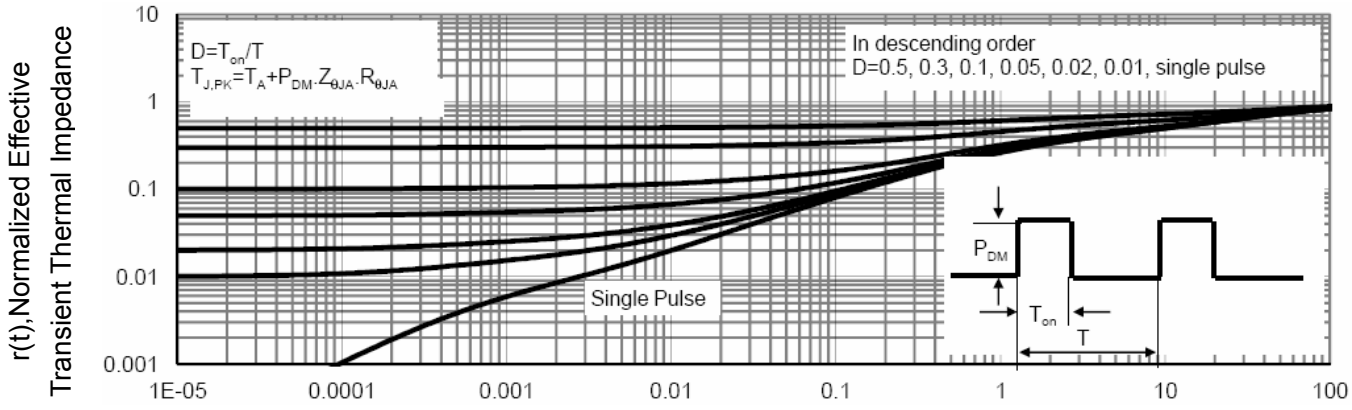
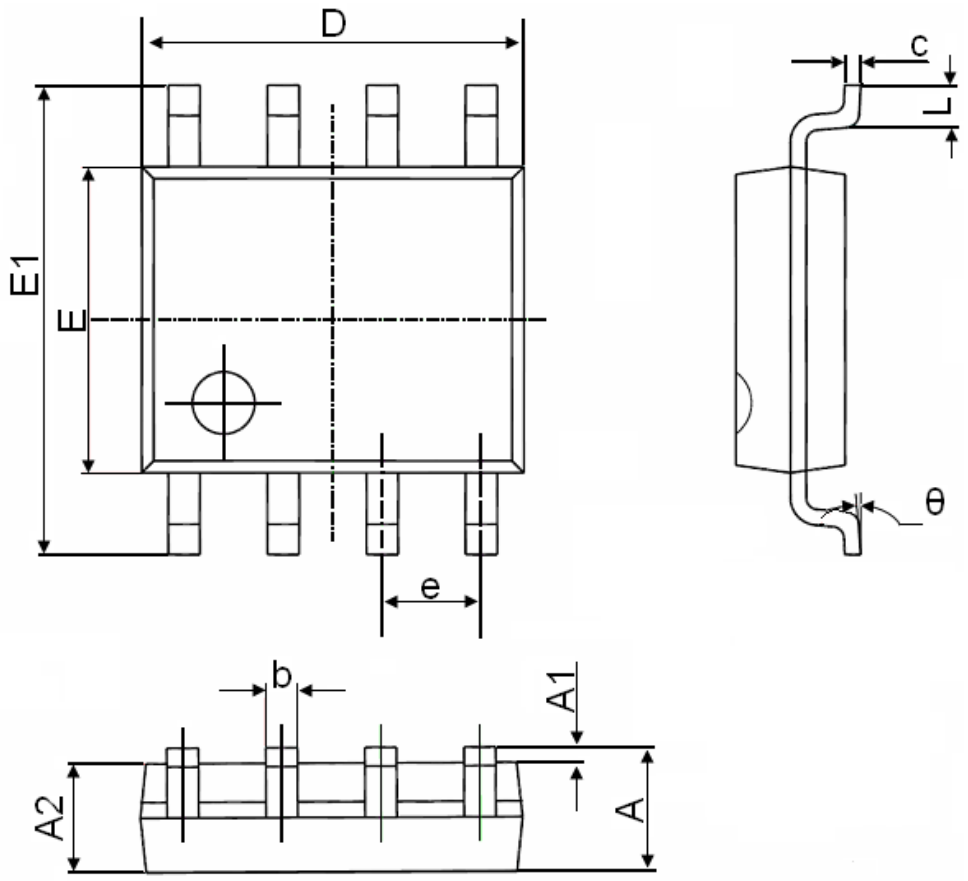



**Figure 11 Normalized Maximum Transient Thermal Impedance**

## SOP-8 Package Information




| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|---|---|---|---|---|
| | Min. | Max. | Min. | Max. |
| A | 1.350 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 |
| b | 0.330 | 0.510 | 0.013 | 0.020 |
| c | 0.170 | 0.250 | 0.006 | 0.010 |
| D | 4.700 | 5.100 | 0.185 | 0.200 |
| E | 3.800 | 4.000 | 0.150 | 0.157 |
| E1 | 5.800 | 6.200 | 0.228 | 0.244 |
| e | 1.270(BSC) | | 0.050(BSC) | |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| θ | 0° | 8° | 0° | 8° |

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